

ULTRAFAST SOFT RECOVERY RECTIFIER DIODE

PRODUCT APPLICATIONS

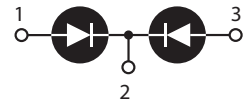
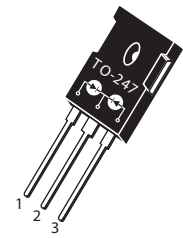
- Anti-Parallel Diode
 - Switchmode Power Supply
 - Inverters
- Free Wheeling Diode
 - Motor Controllers
 - Converters
 - Inverters
- Snubber Diode
- PFC

PRODUCT FEATURES

- Ultrafast Recovery Times
- Soft Recovery Characteristics
- Popular TO-247 Package
- Low Forward Voltage
- Low Leakage Current

PRODUCT BENEFITS

- Low Losses
- Low Noise Switching
- Cooler Operation
- Higher Reliability Systems
- Increased System Power Density



- 1 - Anode 1
- 2 - Common Cathode
- Back of Case - Cathode
- 3 - Anode 2

MAXIMUM RATINGS

 All Ratings Per Leg: $T_C = 25^\circ\text{C}$ unless otherwise specified.

Symbol	Characteristic / Test Conditions	APT30D40BCT(G)	UNIT
V_R	Maximum D.C. Reverse Voltage	400	Volts
V_{RRM}	Maximum Peak Repetitive Reverse Voltage		
V_{RWM}	Maximum Working Peak Reverse Voltage		
$I_{F(AV)}$	Maximum Average Forward Current ($T_C = 141^\circ\text{C}$, Duty Cycle = 0.5)	30	Amps
$I_{F(RMS)}$	RMS Forward Current (Square wave, 50% duty)	73	
I_{FSM}	Non-Repetitive Forward Surge Current ($T_J = 45^\circ\text{C}$, 8.3ms)	320	
T_J, T_{STG}	Operating and Storage Temperature Range	-55 to 175	$^\circ\text{C}$
T_L	Lead Temperature for 10 Sec.	300	

STATIC ELECTRICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT	
V_F	Forward Voltage		$I_F = 30\text{A}$	1.3	1.5	Volts
			$I_F = 60\text{A}$	1.6		
			$I_F = 30\text{A}, T_J = 125^\circ\text{C}$	1.2		
I_{RM}	Maximum Reverse Leakage Current		$V_R = V_R$ Rated		250	μA
			$V_R = V_R$ Rated, $T_J = 125^\circ\text{C}$		500	
C_T	Junction Capacitance, $V_R = 200\text{V}$		60		pF	

DYNAMIC CHARACTERISTICS

APT30D40BCT(G)

Symbol	Characteristic	Test Conditions	MIN	TYP	MAX	UNIT
t_{rr}	Reverse Recovery Time	$I_F = 1A, di_F/dt = -100A/\mu s, V_R = 30V, T_J = 25^\circ C$	-	22		ns
t_{rr}	Reverse Recovery Time		-	32		
Q_{rr}	Reverse Recovery Charge		$I_F = 30A, di_F/dt = -200A/\mu s, V_R = 266V, T_C = 25^\circ C$	-	49	
I_{RRM}	Maximum Reverse Recovery Current	-		3	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 30A, di_F/dt = -200A/\mu s, V_R = 266V, T_C = 125^\circ C$		-	95	
Q_{rr}	Reverse Recovery Charge		-	360		nC
I_{RRM}	Maximum Reverse Recovery Current		-	7	-	Amps
t_{rr}	Reverse Recovery Time	$I_F = 30A, di_F/dt = -1000A/\mu s, V_R = 266V, T_C = 125^\circ C$	-	47		ns
Q_{rr}	Reverse Recovery Charge		-	730		nC
I_{RRM}	Maximum Reverse Recovery Current		-	25		Amps

THERMAL AND MECHANICAL CHARACTERISTICS

Symbol	Characteristic / Test Conditions	MIN	TYP	MAX	UNIT
$R_{\theta JC}$	Junction-to-Case Thermal Resistance			.67	$^\circ C/W$
$R_{\theta JA}$	Junction-to-Ambient Thermal Resistance			40	
W_T	Package Weight		0.22		oz
			5.9		g
Torque	Maximum Mounting Torque			10	lb•in
				1.1	N•m

Microsemi Reserves the right to change, without notice, the specifications and information contained herein.

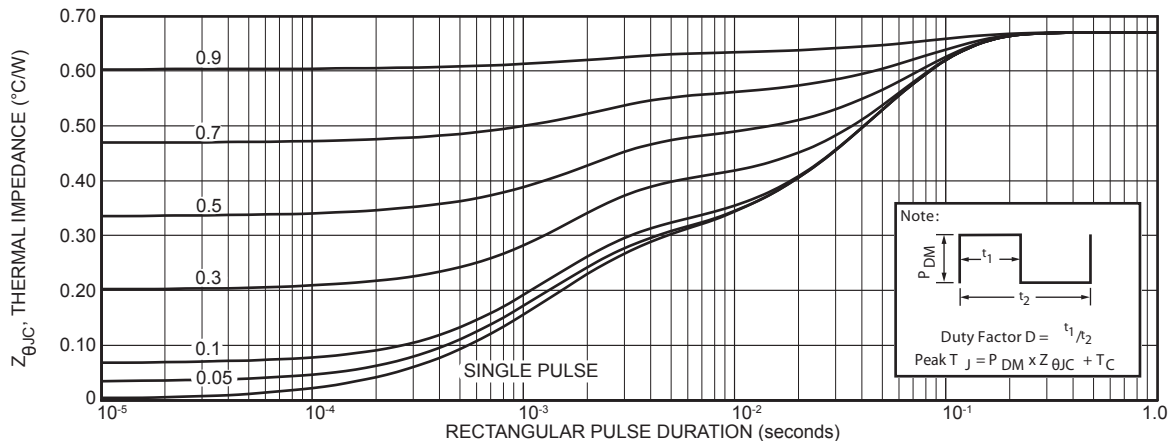


FIGURE 1, MAXIMUM EFFECTIVE TRANSIENT THERMAL IMPEDANCE, JUNCTION-TO-CASE vs. PULSE DURATION

TYPICAL PERFORMANCE CURVES

APT30D40BCT(G)

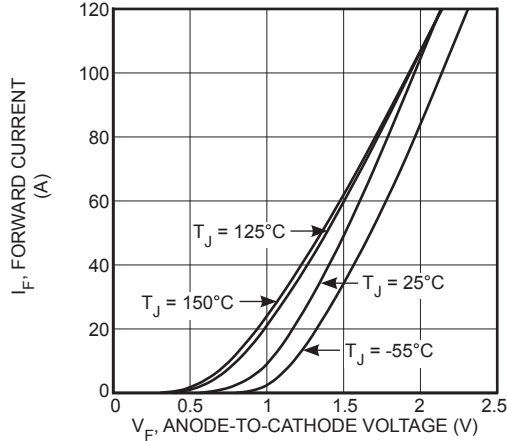


Figure 2. Forward Current vs. Forward Voltage

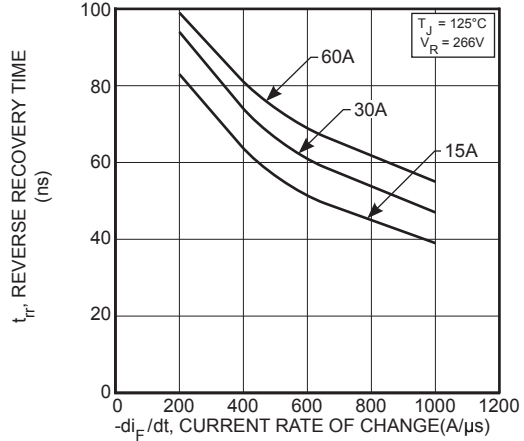


Figure 3. Reverse Recovery Time vs. Current Rate of Change

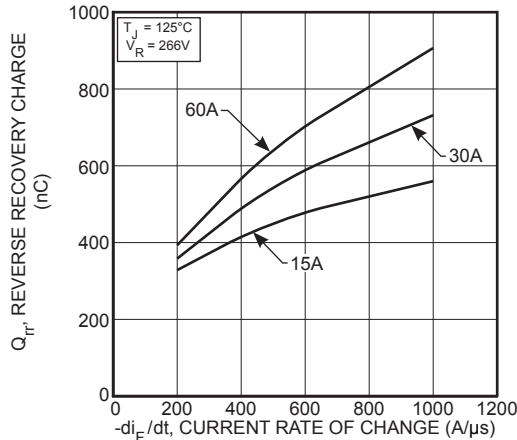


Figure 4. Reverse Recovery Charge vs. Current Rate of Change

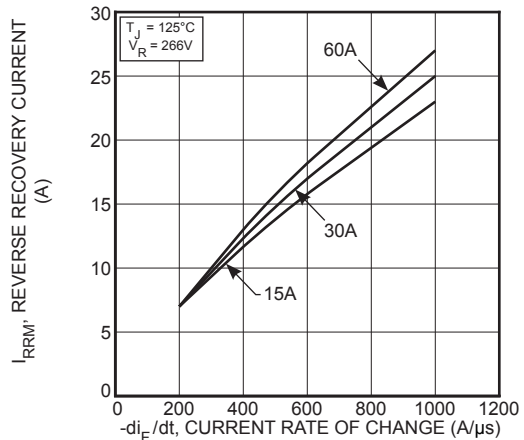


Figure 5. Reverse Recovery Current vs. Current Rate of Change

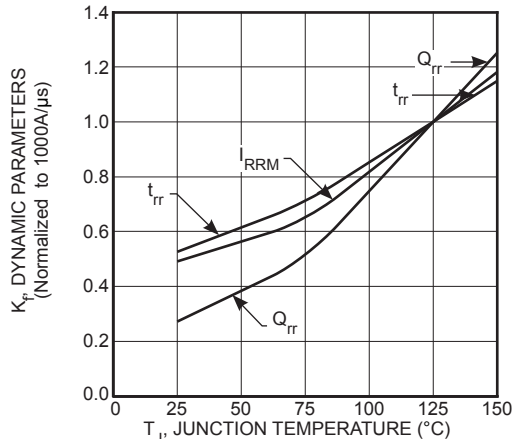


Figure 6. Dynamic Parameters vs. Junction Temperature

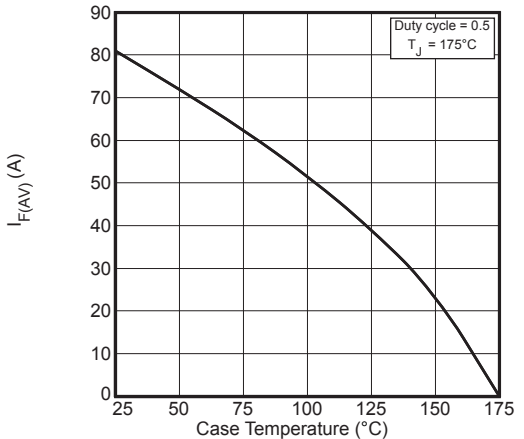


Figure 7. Maximum Average Forward Current vs. Case Temperature

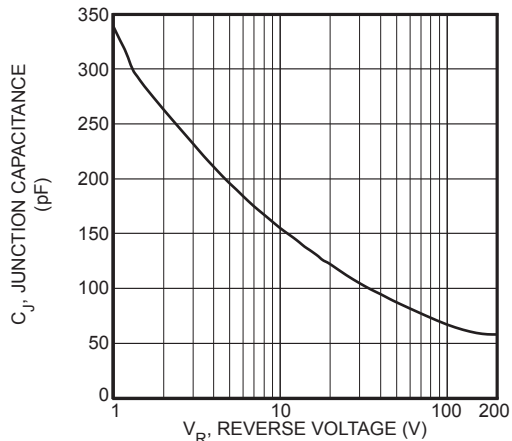


Figure 8. Junction Capacitance vs. Reverse Voltage

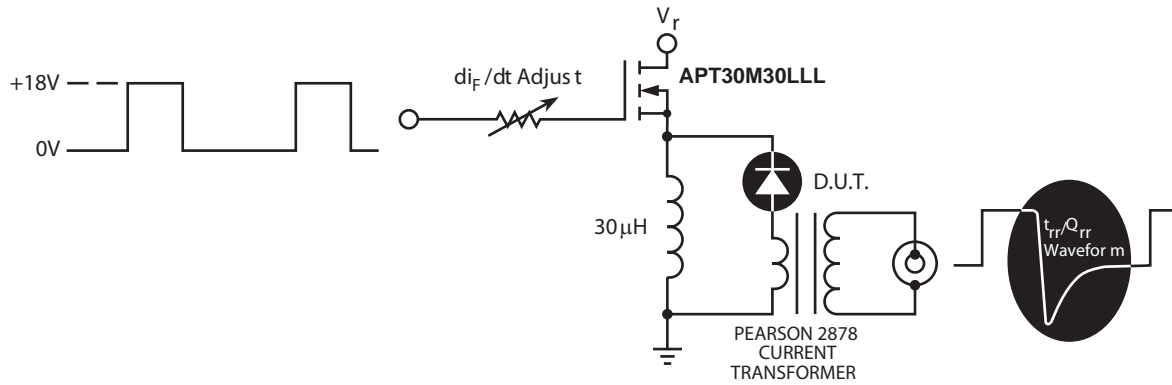


Figure 9. Diode Test Circuit

- 1 I_F - Forward Conduction Current
- 2 di_F/dt - Rate of Diode Current Change Through Zero Crossing.
- 3 I_{RRM} - Maximum Reverse Recovery Current
- 4 t_{rr} - Reverse Recovery Time, measured from zero crossing where the diode current goes from positive to negative, to the point at which the straight line through I_{RRM} and $0.25 I_{RRM}$ passes through zero.
- 5 Q_{rr} - Area Under the Curve Defined by I_{RRM} and t_{rr} .

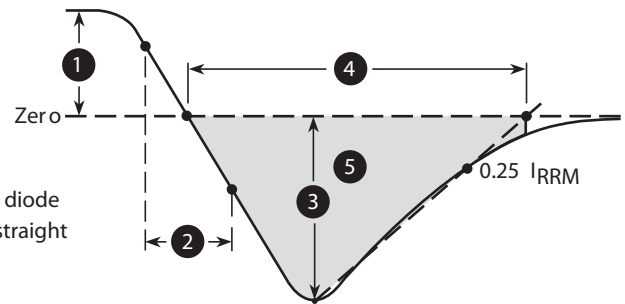
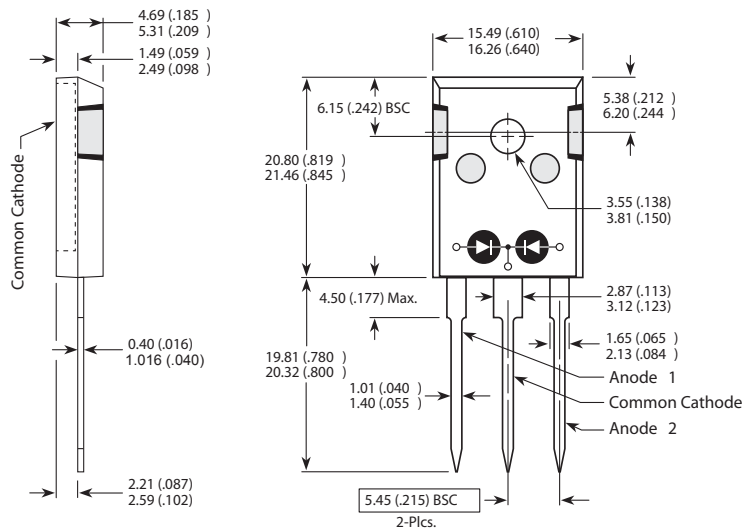


Figure 10. Diode Reverse Recovery and Definitions

TO-247 Package Outline

(e1) SAC: Tin, Silver, Copper



Dimensions in Millimeters and (Inches)

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Rectifiers](#) category:

Click to view products by [Microsemi](#) manufacturer:

Other Similar products are found below :

[70HFR40](#) [RL252-TP](#) [1N5397](#) [NTE5841](#) [SCF5000](#) [1N4005-TR](#) [JANS1N6640US](#) [481235F](#) [RRE02VS6SGTR](#) [067907F](#) [MS306](#) [T110HF60](#)
[T85HFL60S02](#) [US2JFL-TP](#) [A1N5404G-G](#) [CRS04\(T5L,TEMQ\)](#) [ACGRA4007-HF](#) [ACGRB207-HF](#) [CLH03\(TE16L,Q\)](#) [ACGRC307-HF](#)
[ACEFC304-HF](#) [NTE6356](#) [NTE6359](#) [85HFR60](#) [40HFR60](#) [1N1186RA](#) [70HF120](#) [85HFR80](#) [D126A45C](#) [SCF7500](#) [D251N08B](#) [SCHJ22.5K](#)
[SM100](#) [SCPA2](#) [SDHD5K](#) [VS-12FL100S10](#) [ACGRA4001-HF](#) [D1821SH45T PR](#) [D1251S45T](#) [NTE6358](#) [NTE6162](#) [NTE5850](#) [SKN 5/08](#)
[NTE5819](#) [NTE5837](#) [NTE5892](#) [NTE5894](#) [NTE5900](#) [NTE5911](#) [NTE5915](#)